

Vishay Siliconix

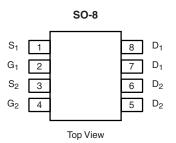
Dual N-Channel 100-V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	
100	0.150 at V _{GS} = 10 V	2.6	
	0.180 at V _{GS} = 6 V	2.4	

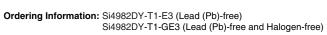
FEATURES

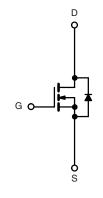
- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC











N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	100	v	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T 150 °C)	T _A = 25 °C		2.6		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	- I _D	2.1		
Pulsed Drain Current		I _{DM}	20	A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	1.7		
	T _A = 25 °C	PD	2.0	w	
Maximum Power Dissipation ^a	T _A = 70 °C		1.3		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Limit	Unit	
Maximum Junction-to-Ambient ^a	R _{thJA}	62.5	°C/W	

Notes:

a. Surface Mounted on FR4 board, t \leq 10 s.

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Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit
Static	<u> </u>					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2			V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V			1	
		V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 55 °C			20	μA
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	15			А
Drain-Source On-State Resistance ^b	R _{DS(on)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.6 \text{ A}$		0.130	0.150	Ω
		$V_{GS} = 6 V, I_D = 2.4 A$		0.140	0.180	
Forward Transconductance ^b	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 2.6 \text{ A}$		11		S
Diode Forward Voltage ^b	V _{SD}	$I_{\rm S} = 1.7$ A, $V_{\rm GS} = 0$ V			1.2	V
Dynamic ^a			1			
Gate Charge	Qg			15	30	
Gate-Source Charge	Q _{gs}	V_{DS} = 50 V, V_{GS} = 10 V, I_D = 2.6 A		2.7		nC
Gate-Drain Charge	Q _{gd}			4.0		
Gate Resistance	Rg		1		4.4	Ω
Turn-On Delay Time	t _{d(on)}			10	20	
Rise Time	t _r	V_{DD} = 50 V, R_L = 50 Ω		10	20	ns
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		30	60	
Fall Time	t _f			10	20	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dl/dt = 100 A/μs		60	90	

Notes:

a. For design aid only; not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

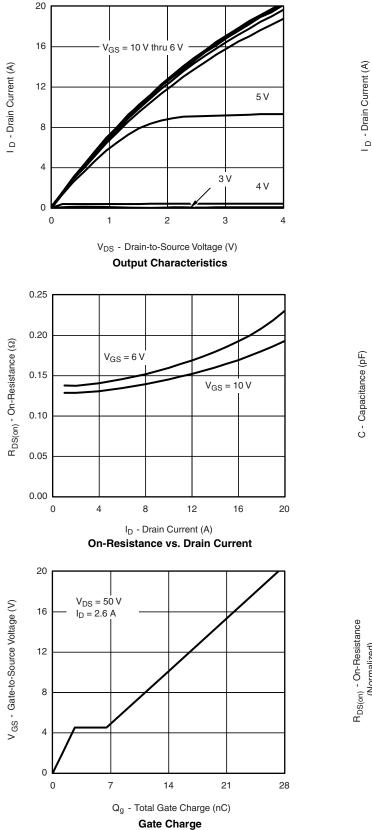
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

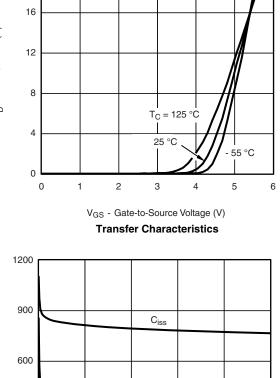
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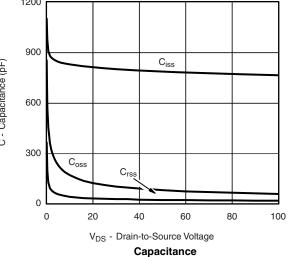
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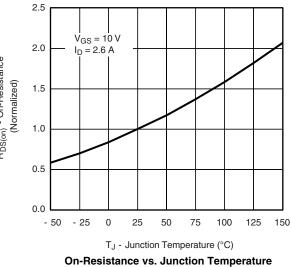
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





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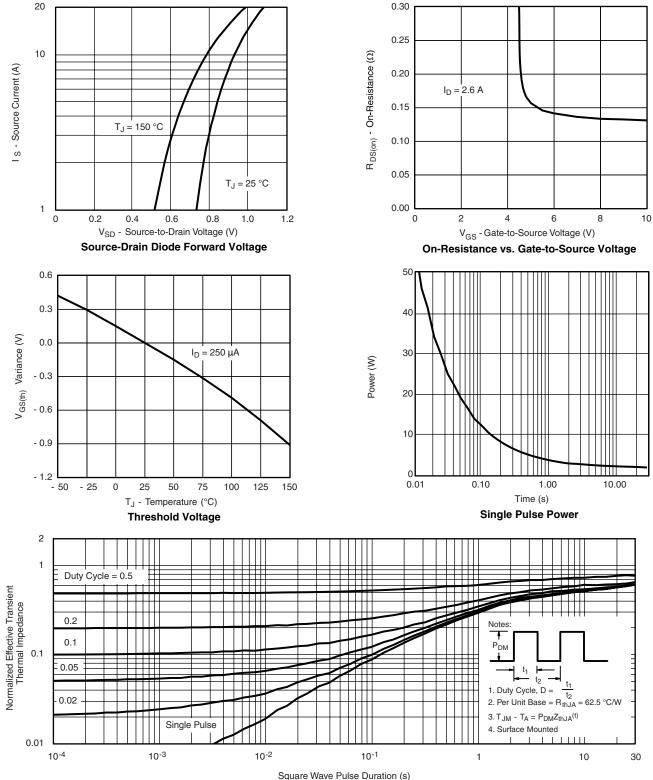
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg270748.



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